

### **Feature**

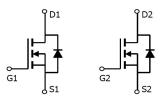
20V,6.0A

$$\begin{split} &R_{\text{DS (ON)}} < 26\text{m}\,\Omega\,\text{@V}_{\text{GS}} = 4.5\text{V} & \text{TYP=20 m}\,\Omega \\ &R_{\text{DS (ON)}} < 33\text{m}\,\Omega\,\text{@V}_{\text{GS}} = 2.5\text{V} & \text{TYP=26 m}\,\Omega \end{split}$$

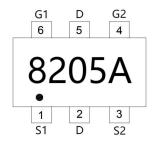
- Advanced Trench Technology
- Lead free product is acquired
- Low gate charge

## **Application**

- Interfacing Switching
- Load Switching
- Power management



#### **Schematic Diagram**



Marking and pin Assignment

## **Package Marking and Ordering Information**

<b>Device Marking</b>	Device	Device Package	Reel Size	Tape width	Quantity (PCS)	
8205A	AP8205A	SOT23-6		-	3000	

## ABSOLUTE MAXIMUM RATINGS (T<sub>J</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	20	V
Gate-Source Voltage	V <sub>GS</sub>	±12	V
Continuous Drain Current (T <sub>a</sub> =25℃)	I <sub>D</sub>	6.0	А
Continuous Drain Current (T <sub>a</sub> =70°C)	I <sub>D</sub>	4.0	А
Pulsed Drain Current	I <sub>DM</sub>	24	А
Power Dissipation	P <sub>D</sub>	2.5	W
Thermal Resistance from Junction to Ambient <sup>(4)</sup>	$R_{\theta JA}$	50	°C/W
Junction Temperature	TJ	150	$^{\circ}$
Storage Temperature	T <sub>STG</sub>	-55~ +150	${\mathbb C}$



# MOSFET ELECTRICAL CHARACTERISTICS(T<sub>J</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Туре	Max	Unit	
Static Characteristics							
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V, I_D = 250\mu A$	20	-	-	V	
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> =20V, V <sub>GS</sub> = 0V	-	-	1	μA	
Gate-body leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 10V, V_{DS} = 0V$	-	-	±100	nA	
Gate threshold voltage <sup>(3)</sup>	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	0.5	0.7	1.2	V	
Drain-source on-resistance <sup>(3)</sup>	В	V <sub>GS</sub> =4.5V, I <sub>D</sub> =4A	-	20	26	mΩ	
Drain-source on-resistance.	R <sub>DS(on)</sub>	V <sub>GS</sub> =2.5V, I <sub>D</sub> =3A	-	26	33		
Dynamic characteristics							
Input Capacitance	C <sub>iss</sub>		-	1035	-	pF	
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 20V, V_{GS} = 0V, f = 1MHz$	-	320	-		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	-	150	-		
Switching characteristics							
Turn-on delay time	t <sub>d(on)</sub>		-	30	-		
Turn-on rise time	t <sub>r</sub>	$V_{DD}=10V, I_{D}=1A,$	-	70	-	ns	
Turn-off delay time	t <sub>d(off)</sub>	$V_{GS}$ =5.0V, $R_{G}$ =6 $\Omega$	-	40	-		
Turn-off fall time	t <sub>f</sub>	-	-	65	-		
Total Gate Charge	Qg	VD0 40V/ ID 0.54	-	15	-		
Gate-Source Charge	Qgs	VDS=10V, ID=3.5A,	-	2.9	-	nC	
Gate-Drain Charge	Qgd	- VGS=4.5V	-	3.6	-		
Source-Drain Diode characteristics							
Diode Forward voltage <sup>(3)</sup>	V <sub>DS</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =1.7A	-	-	1.2	V	
Diode Forward current <sup>(4)</sup>	Is		-	-	6.0	Α	

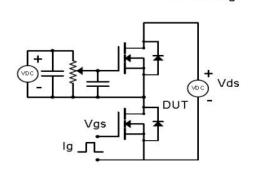
#### Notes:

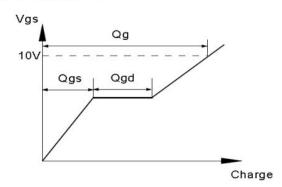
- 1. Repetitive Rating: pulse width limited by maximum junction temperature
- 2. Pulse Test: pulse width≤300µs, duty cycle≤2%
- 3. Surface Mounted on FR4 Board,t≤10 sec



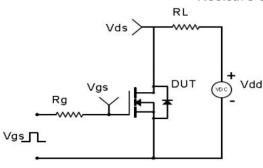
### **Test Circuit & Waveform**

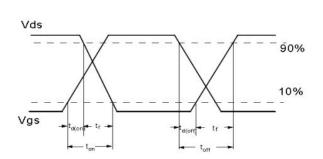
## Gate Charge Test Circuit & Waveform



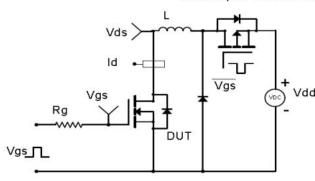


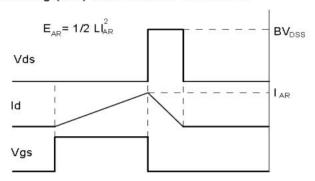
Resistive Switching Test Circuit & Waveforms



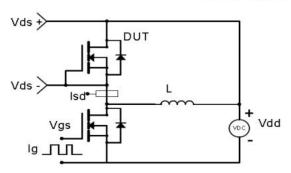


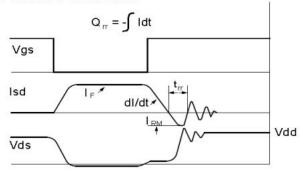
### Unclamped Inductive Switching (UIS) Test Circuit & Waveforms





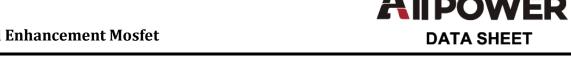
### Diode Recovery Test Circuit & Waveforms

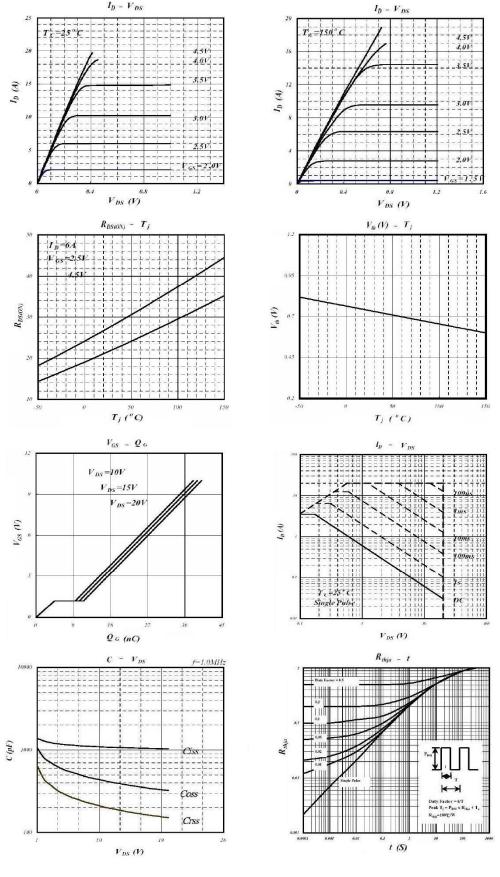






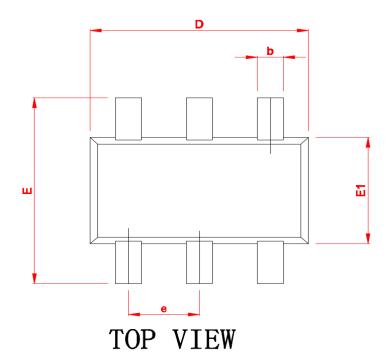
# **Typical Performance Characteristics**

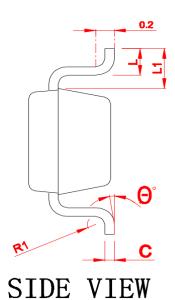


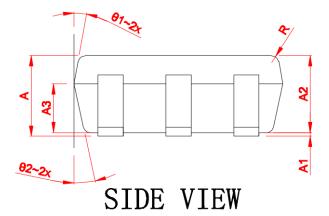




# **SOT23-6 Package Information**







0)////001	MILLIMETER				
SYMBOL	MIN	NOM	MAX		
Α	1.10	1.15	1.25		
* A1	0.02	0.06	0.10		
* A2	1.05	1.10	1.15		
A3	0.60	0.65	0.70		
* b	0.32	0.35	0.48		
* C	0.152REF				
* D	2.87	2.92	2.97		
* E	2.60	2.80	3.00		
* E1	1.55	1.60	1.65		
* е	0.95BSC				
* L	0.35 0.45		0.55		
L1	0.60 REF				
R	0.10 REF				
R1 0.12 REF			•		
* Θ	0°	3°	6°		
Θ1	7°BSC				
Θ2	10°BSC				



# **Revision History**

Revision	Release	Remark	
V1.0	2024/03/16	Initial Release	

## **Disclaimer**

The information given in this document describes the independent performance of the product, but similar performance is not guaranteed under other working conditions, and cannot be guaranteed when installed with other products or equipment. To achieve the required performance of the product in actual scenarios, the customer should conduct a complete application test to assess the functionality of the product.

Allpower assumes no responsibility for equipment failures result from using products at values that exceed the ratings, operating conditions, or other parameters listed in the product specifications.

The product described in this specification is not applicable for aerospace or other applications which

requires high reliability. Customers using or selling these products for use in medical, life-saving, or life-sustaining applications do so at their own risk and agree to fully indemnify.

Due to product or technical improvements, the information described or contained herein may be changed without prior notice.